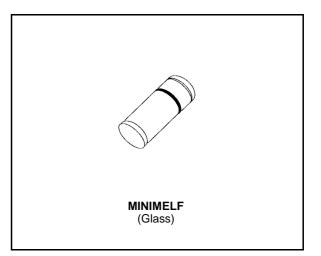


## TMMBAT 47 TMMBAT 48

### SMALL SIGNAL SCHOTTKY DIODES



#### DESCRIPTION

General purpose, metal to silicon diodes featuring very low turn-on voltage and fast switching. These devices have integrated protection against excessive voltage such as electrostatic discharges.

#### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	TMMBAT47	TMMBAT48	Unit	
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage	20	40	V	
١ <sub>F</sub>	Forward Continuous Current	35	mA		
I <sub>FRM</sub>	$\begin{array}{ll} \mbox{Repetitive Peak Fordward Current} & t_p \leq 1s \\ \delta \leq 0.5 \end{array}$		1		A
I <sub>FSM</sub>	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$		7.5		А
			1.5		
P <sub>tot</sub>	Power Dissipation	330		mW	
T <sub>stg</sub> Tj	Storage and Junction Temperature Range	- 65 to 150 - 65 to 125		°C °C	
TL	Maximum Temperature for Soldering during	260		°C	

#### THERMAL RESISTANCE

Symbol	Test Conditions	Value	Unit
R <sub>th(j-l)</sub>	Junction-leads	300	°C/W

#### TMMBAT 47/TMMBAT 48

### **ELECTRICAL CHARACTERISTICS**

### STATIC CHARACTERISTICS

Symbol		Test Conditions	6	Min.	Тур.	Max.	Unit
$V_{BR}$	$T_j = 25^{\circ}C$	$I_R = 10 \mu A$	TMMBAT47	20			V
	T <sub>j</sub> = 25°C	I <sub>R</sub> = 25μΑ	TMMBAT48	40			
V <sub>F</sub> *	T <sub>j</sub> = 25°C	$I_F = 0.1 \text{mA}$	All Types			0.25	V
	T <sub>j</sub> = 25°C	$I_F = 1 m A$				0.3	
	T <sub>j</sub> = 25°C	$I_F = 10 \text{mA}$				0.4	
	T <sub>j</sub> = 25°C	$I_F = 30 \text{mA}$	TMMBAT47			0.5	
	T <sub>j</sub> = 25°C	I <sub>F</sub> = 150mA				0.8	
	T <sub>j</sub> = 25°C	I <sub>F</sub> = 300mA				1	
	T <sub>j</sub> = 25°C	$I_F = 50 \text{mA}$	TMMBAT48			0.5	
	T <sub>j</sub> = 25°C	$I_F = 200 \text{mA}$				0.75	
	T <sub>j</sub> = 25°C	$I_F = 500 \text{mA}$				0.9	
I <sub>R</sub> *	T <sub>j</sub> = 25°C	V <sub>R</sub> = 1.5V	All Types			1	μA
	$T_j = 60^{\circ}C$					10	
	T <sub>j</sub> = 25°C	V <sub>R</sub> = 10V	TMMBAT47			4	
	$T_j = 60^{\circ}C$					20	
	T <sub>j</sub> = 25°C	V <sub>R</sub> = 20V				10	
	$T_j = 60^{\circ}C$					30	
	T <sub>j</sub> = 25°C	V <sub>R</sub> = 10V	TMMBAT48			2	
	$T_j = 60^{\circ}C$					15	
	T <sub>j</sub> = 25°C	V <sub>R</sub> = 20V				5	
	$T_j = 60^{\circ}C$					25	
	T <sub>j</sub> = 25°C	V <sub>R</sub> = 40V				25	
	T <sub>j</sub> = 60°C					50	

### DYNAMIC CHARACTERISTICS

Symbol	Test Conditions	Min.	Тур.	Max.	Unit
С	$T_j = 25^{\circ}C$ $V_R = 0V$ $f = 1$	f = 1MHz			pF
	$T_j = 25^{\circ}C$ $V_R = 1V$		12		
t <sub>rr</sub>	$T_j = 25^{\circ}C$ $I_F = 10mA$ $V_R = 1V$ $i_{rr} = 1mA$	R <sub>L</sub> = 100Ω	10		ns

\* Pulse test:  $t_p \le 300 \mu s \quad \delta < 2\%$ .

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Figure 1. Forward current versus forward voltage at different temperatures (typical values).

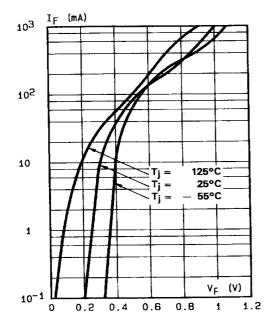


Figure 2. Forward current versus forward voltage (typical values).

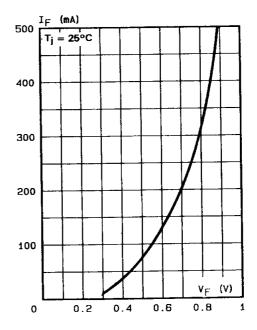


Figure 3. Reverse current versus junction temperature.

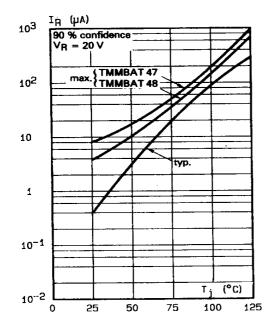
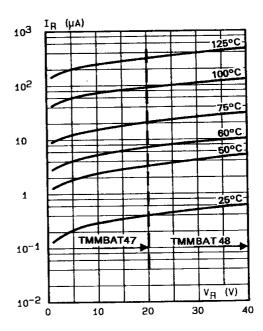


Figure 4. Reverse current versus continuous reverse voltage (typical values).



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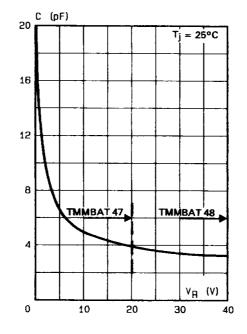


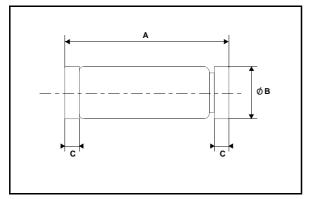
Figure 5. Capacitance C versus reverse applied voltage  $V_{\rm R}$  (typical values).

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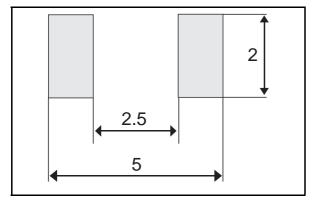
#### PACKAGE MECHANICAL DATA

#### **MINIMELF Glass**



	DIMENSIONS						
REF.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	3.30	3.40	3.6	0.130	0.134	0.142	
В	1.59	1.60	1.62	0.063	0.063	0.064	
С	0.40	0.45	0.50	0.016	0.018	0.020	
D		1.50			0.059		

#### FOOT PRINT DIMENSIONS (Millimeter)



Marking: ring at cathode end. Weight: 0.05g

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